

SS13HE, NRVBSS13HE Series

Table 1. ABSOLUTE MAXIMUM RATINGS Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Value			Unit
		SS13HE	SS14HE, SASS14HE	SS16HE	
V_{RRM}	Maximum Repetitive Peak Reverse Voltage	30	40	60	V
V_R	Reverse Voltage	30	40	60	V
$I_{F(AV)}$	Maximum Average Forward Rectified Current	1			A
I_{FSM}	Peak Forward Surge Current: 8.3 ms Single Half Sine-Wave Superimposed on Rated Load	25			A
T_J	Operating Junction Temperature Range	-55 to +150			$^\circ\text{C}$
T_{STG}	Storage Temperature Range	-55 to +150			$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Table 2. THERMAL CHARACTERISTICS (Note 1) Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit
Ψ_{JL}	Junction-to-Lead Thermal Resistance Thermocouple Soldered to Cathode	21	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Junction-to-Ambient Thermal Resistance (Note 1)	199	$^\circ\text{C}/\text{W}$

1. Per JE5D51-3 Recommended Thermal Test Board. Device mounted on FR-4 PCB, board size = 76.2 mm x 114.3 mm

Table 3. ELECTRICAL CHARACTERISTICS Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_F	Instantaneous Forward Voltage (Note 2)	$I_F = 0.5\text{ A}, T_J = 25^\circ\text{C}$	SS13HE, SS14HE, SASS14HE		0.41		V
		$I_F = 0.5\text{ A}, T_J = 125^\circ\text{C}$			0.31		
		$I_F = 1.0\text{ A}, T_J = 25^\circ\text{C}$			0.46	0.55	
		$I_F = 1.0\text{ A}, T_J = 125^\circ\text{C}$			0.40	0.50	
		$I_F = 0.5\text{ A}, T_J = 25^\circ\text{C}$	SS16HE		0.51		
		$I_F = 0.5\text{ A}, T_J = 125^\circ\text{C}$			0.45		
		$I_F = 1.0\text{ A}, T_J = 25^\circ\text{C}$			0.61	0.68	
		$I_F = 1.0\text{ A}, T_J = 125^\circ\text{C}$			0.54	0.60	
I_R	Reverse Current at Rated V_R	$T_J = 25^\circ\text{C}$	SS13HE, SS14HE, SASS14HE		5.0	50	μA
		$T_J = 125^\circ\text{C}$			3.0	10	mA
		$T_J = 25^\circ\text{C}$	SS16HE		2.0	50	μA
		$T_J = 125^\circ\text{C}$			1.5	10	mA
T_{rr}	Reverse Recovery Time	$I_F = 0.5\text{ A}, I_R = 1.0\text{ A},$ $I_{rr} = 0.25\text{ A}$	SS13HE, SS14HE, SASS14HE		5.6		ns
			SS16HE		8.3		
C_J	Junction Capacitance	$V_R = 4.0\text{ V}, f = 1\text{ MHz}$	SS13HE, SS14HE, SASS14HE		55		pF
			SS16HE		43		

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Pulse test with $PW = 300\ \mu\text{s}$, 1% duty cycle

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TYPICAL PERFORMANCE CHARACTERISTICS

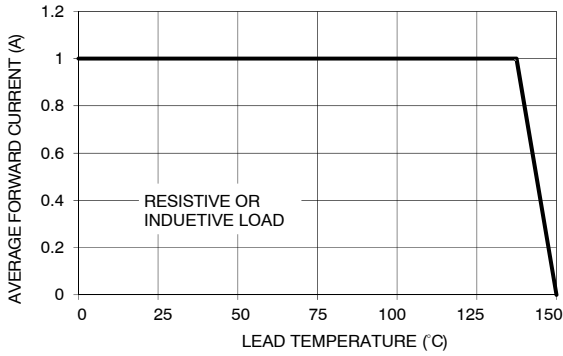


Figure 1. Forward Current Derating Curve

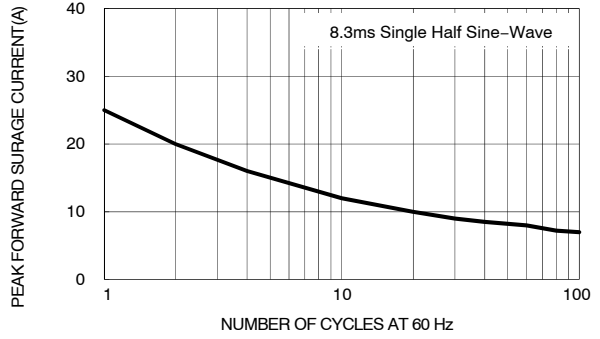


Figure 2. Maximum Non-Repetitive Forward Surge Current

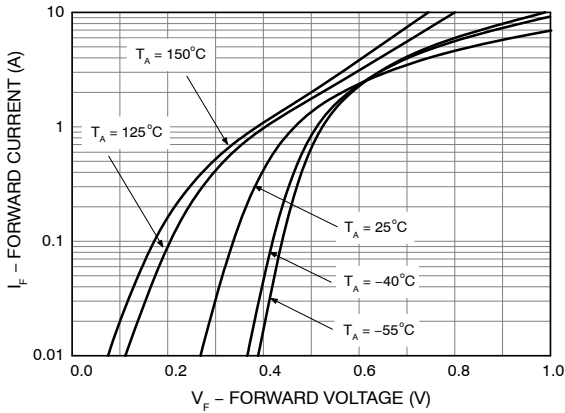


Figure 3. Typical Forward Characteristics - SS13HE / SS14HE

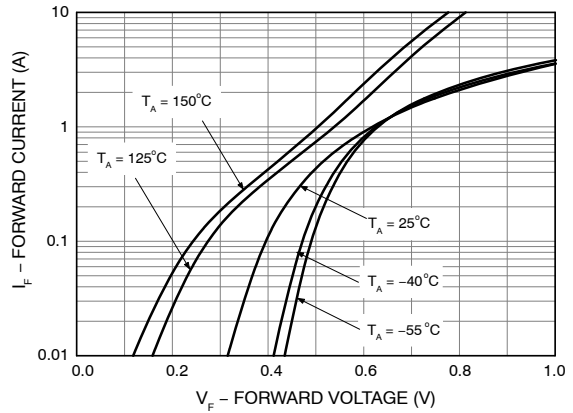


Figure 4. Typical Forward Characteristics - SS16HE

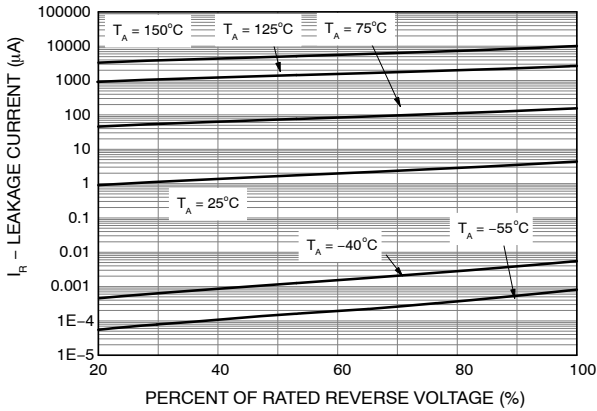


Figure 5. Typical Reverse Characteristics - SS13HE / SS14HE

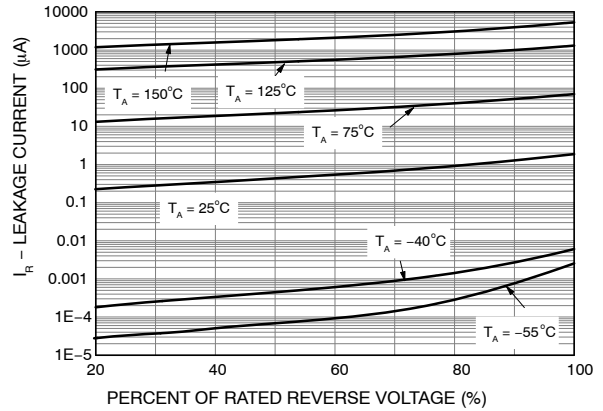


Figure 6. Typical Reverse Characteristics - SS16HE

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TYPICAL PERFORMANCE CHARACTERISTICS

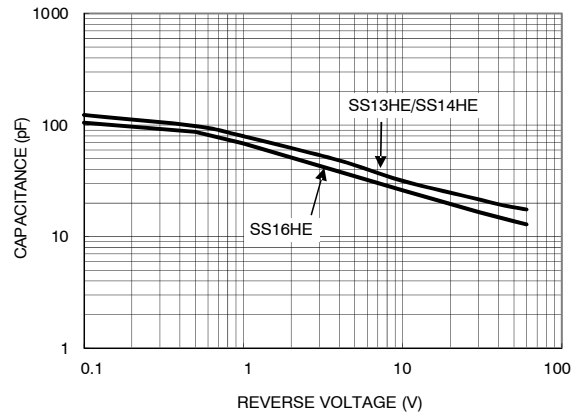


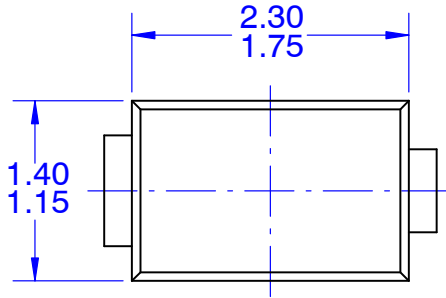
Figure 7. Typical Junction Capacitance

MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

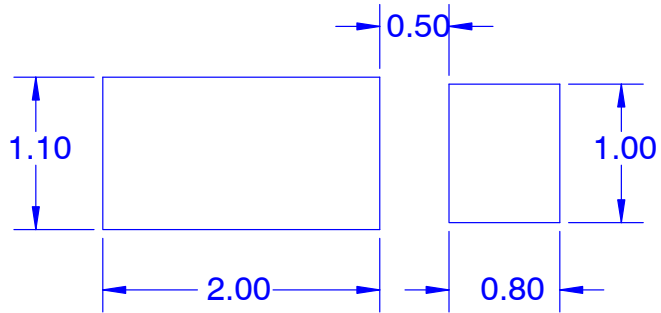


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CASE 477AD
ISSUE O

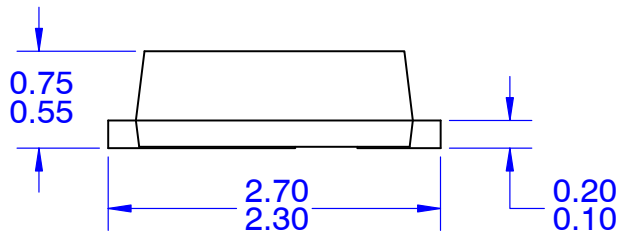
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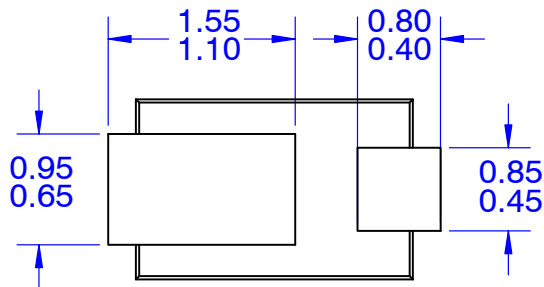
TOP VIEW



LAND PATTERN RECOMMENDATION



FRONT VIEW



BOTTOM VIEW

NOTES:

- A. THIS PACKAGE DOES NOT CONFORM TO ANY STANDARDS.
- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUSIONS.

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